







## NATIONAL INSTITUTE OF TECHNOLOGY WARANGAL

Warangal - 506 004, Telangana

Synergistic Training Program Utilizing the Scientific and Technological Infrastructure (STUTI)

# Call for Registration and Participation Training Program on R&D Equipment

Theme: Characterization of Materials/Compounds by using Advanced Instruments

Program Dates: April 11th to 17th 2023

Venue: Indian Institute of Technology Delhi, (Sonipat Campus)



Register before: 31st March 2023



Scan to Register

No Registration Fee

Click to register: <a href="https://forms.gle/LzQ8pc36D6Twza4p9">https://forms.gle/LzQ8pc36D6Twza4p9</a>

## **Objectives of the Program:**

To enable the participants to understand the principles, applications, and hands-on experience on sophisticated analytical instruments.

To gain knowledge about the in-depth analysis of the characterization techniques using high-end analytical instruments.

To interact with eminent professors/ scientists/ industrial research personnel and discuss real-time research and make collaborations.

To encourage the participants to utilize the facilities and enhance the research temper.

To create a research-friendly atmosphere by letting the creative minds of the country exchange ideas and share their knowledge among their fellow participants.

## **Eligibility Criteria:**

Faculty / Scientists / Post-Doc Fellows / Ph.D. Fellows / Industry Persons / M.Sc. students/M.Tech. Students who are actively involved in research and development (R&D) in the fields of Chemical Sciences, or any relevant area.

## **Important Instruction:**

Fill in the prescribed bio-data form attached with this brochure and get it endorsed by the head of the institution. And keep the scanned copy ready, which needs to be uploaded during registration.

Organized by
Indian Institute of Technology Delhi (Spoke)
NIT Warangal, Telangana (Hub)
Funded by
DST, Govt of India

#### **About Indian Institute of Technology Delhi:**

Indian Institute of Technology Delhi is one of the 23 IITs created to be Centres of Excellence for training, research and development in science, engineering and technology in India.

Established as College of Engineering in 1961, the Institute was later declared as an Institution of National Importance under the "Institutes of Technology (Amendment) Act, 1963" and was renamed as "Indian Institute of Technology Delhi". It was then accorded the status of a Deemed University with powers to decide its own academic policy, to conduct its own examinations, and to award its own degrees. The primary campus of IIT Delhi is located in Hauz Khas, South Delhi, with Sonipat and Jhajjar (land acquired only) being the two satellite campuses. Currently, IIT delhi have 16 Departments, 09 Centres, Schools and 02 Joint degree programme with a total on roll students of 12064.

#### **About NIT Warangal:**

National Institute of Technology Warangal, formerly known as Regional Engineering College, was established in 1959. Over the years it has developed into a premier institute of higher learning and is ranked among the top technical education institutions in India. There are 14 Departments offering eight undergraduate, 35 post-graduate programs and guiding 952 PhD scholars besides post-doctoral programs. About 6864 students across the country including international students' study on the campus. It is a fully residential campus spread across 250 acres with excellent in frastructure in the form of state-of-the-art library, seminar halls, guest houses and research laboratories.

#### **STUTI Team:**

#### Patron,

Prof. Rangan Banerjee.

Director, Indian Institute of Technology Delhi

#### Chairman

Prof. N. V. Ramana Rao,

Director, NIT Warangal

#### Co-Chairmen

**Prof.** Naresh Bhatnagar, Dean (R&D), IIT Delhi

**Prof.** Somasekhar V. T. Dean (R&C), NIT Warangal

Prof. Rajender Singh Associate Dean (R&D), IIT Delhi

#### Convenor

Sri S Goverdhan Rao, Registrar, NIT Warangal

**Prof. Samir Sapra**, Head CRF and PI, SATHI

Prof. Manidipa Banerjee, Assoc Head CRF &Co

PI, SATHI

#### Principal Investigator

Prof. N. Narasaiah, Dept of MME, NITW & PI, STUTI

#### Co-Principal Investigator

Dr. T K Sai, PSO, CRIF, NITW & Co-PI, STUTI

#### **Program Coordinators**

Dr Bhupender Singh

Principal Technical Officer, CRF, IIT Delhi

#### Sri D Ravikumar

Technical Officer, CRIF, NIT Warangal

#### Note:

The shortlisted candidates will be intimated through mail. All the selected participants have to submit the uploaded bio-data form physically for the confirmation of participation.

Non-local participants are eligible for FREE boarding/lodging at Indian Institute of Technology Delhi,(Sonipat Campus) on double sharing basis.

For domestic travel of participants, the reimbursement for train/bus tickets is allowed as per actual up to 3AC fare (for outstation participants only).

#### **Contact Us:**

#### Sri D Ravikumar

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#### Dr. Bhupender singh

Principal Technical Officer CRF, IIT Delhi

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#### **About STUTI:**

The Scheme 'Synergistic Training program Utilizing the Scientific and Technological Infrastructure' (STUTI) is intended to build human resource and its knowledge capacity through open access S&T Infrastructure across the country. As a complement to the various schemes of DST funding for expansion of R&D Infrastructure at academic institutions, STUTI scheme envisions a hands-on training program and sensitization of the state-of-the-art equipment as well as towards sharing while ensuring transparent access of S&T facilities.

## **Instruments covered for training:**

- **❖** Transmission Electron Microscope (TEM)
- **♦** Physical Property Measurement System (PPMS)
- **❖** Time of Flight Secondary Mass Spectroscopy (TOF-SIMS)
- **❖** Small Angle X-ray Scattering (SAXS)
- **\*** X-ray Photoelectron Spectroscopy (XPS)
- **❖** X-Ray Diffractometer (XRD)
- **Equipment Name:** Transmission Electron Microscope (TEM)
- Make: Jeol
- **♣** Model: JEM-ARM200F NEOARM
- **Applications:** 
  - 1. Study of crystal structure
  - 2. Defects study
  - 3. Grain boundary study
  - 4. Tomography
  - 5. Electron Energy Loss Spectroscopy





- **Equipment Name:** Small Angle X-ray Scattering (SAXS)
- **Make:** Anton Paar
- **♣** Model: SAXS point 2.0
- **Applications:** 
  - 1. nanoparticle (1-100 nm) size distributions
  - 2. shape
  - 3. pore sizes
  - 4. particle density
  - 5. inter particle distance of partially ordered materials
  - 6. surface to volume ratio

**EquipmentName:** Physical Property Measurement System (PPMS)

**Make:** Cryogenic Ltd. (the UK)

**♣** Model: CFMS 14T

## Applications:

1. Magnetic transport properties (M-T, M-H, ACS)

2. Electrical Transport Properties (Hall, MR, R-T, AC resistivity)

3. Thermal Transport properties (Seebeck Coefficient, Thermal conductivity, Heat capacity)





**Equipment** Name: X-ray Photoelectron Spectroscopy (XPS)

**Make:** Kratos Analytical Ltd

♣ <u>Model:</u> AXIS Supra

## **Applications:**

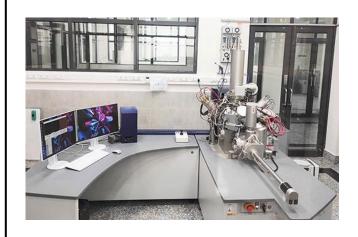
1. Insight into the chemical composition, elemental and chemical

distribution of species, defect sites and functional groups

- 2. Surface chemistry of 2D materials and nanomaterials
- 3. Biomaterials
- 4. Catalysis
- 5. Thin films and multilayer films
- 6. Surface properties of wood, wood fibre and biopolymer samples
- 7. Polymers and Battery materials
- **Equipment Name:** Time of Flight Secondary Mass Spectroscopy (TOF-SIMS)
- 🖶 <u>Make:</u> IONTOF GmbH Germany
- **♣** Model: TOF-SIMS 5

## Applications:

- 1. Mass spectrum study of elements and organic materials
- 2. Mapping of elements and organic species on the surfaces
- 3. Composition & impurity measurements of thin films
- 4. Failure and root cause analysis of devices &materials
- 5. Dopant & impurity depth profiling.





- **4** Equipment Name: X-ray Diffractometer
- **♣** <u>Make:</u> Malvern PAN analytical
- **Model:** Empyrean

## **Applications:**

- 1. Powder diffraction in either reflection or transmission geometries employing 0D.
- 2. Medium and high-resolution X-ray diffraction of Thin films including symmetrical, asymmetrical and grazing incidence diffraction, x-ray reflectivity, texture, stress, rocking curves, fast reciprocal lattice maps.
- 3. Medium and high-resolution X-ray diffraction studies of thin films and layered materials in the temperature range of 12-770 K ( $-261-500^{\circ}$ C).

## **BIODATA FOR STUTI-21 DST TRAINING PROGRAM**

Prof./Dr./Mr./Ms.												
DESIGNATION DESIGNATION												
ORGANIZATION												
DATE OF ENTRY IN SERVICE												
CATEGORY	(GENERA	L/SC/S	Г / ОВС	C)								
DATE OF BIRTH												
SEX (M/F)	EX (M/ F)											
COMPLETE ADDRESS (OFFICE)												
COMPLETE ADDRESS (RESIDENCE)												
CONTACT DETAILS	PHONE (	O)	PHO	NE (R)		MOE	BILE N	No.	E-M	AIL		

EDUCATIONAL / PROFESSIONAL QUALIFICATIONS (GRADUATION ONWARDS)							
Sr. No.	EXAMINATION/	UNIVERSITY/	YEAR	SUBJECT	DIVISION/PERCENTA		
	DEGREE	INSTITUTE			GE OF MARKS		

EXPER	EXPERIENCE						
Sr. No.	NAME OF THE ORGANISATION	DESIGNATION	FROM	TO	DUTY PERFORMED		

TRAINI	TRAINING ATTENDED							
Sr. No.	YEAR	NAME OF THE TRAINING PROGRAMME	NAME OF THE INSTITUTE	DURATION				

		ERIENCE		
Sr. No.	YEAR	TOPIC OF RESEARCH	SPONSORING AGENCY	GIST OF REASEARCH
	<u> </u>			
PAPER	PUBLISH	ED / PATENT FILED/OBTAINED		
Sr. No.	YEAR	TOPIC OF PAPER/ BOOK	GIST OF PAPER	NAME OF JOURNAL/
				MAGZINE/ PUBLISHER
iefly giv	e details	of significant contribution made	by you in the field of Science of	& Technology during your
reer. (10	00 words)			
Date	<b>:</b> :			
Plac				
				(Signature of the Particip

(Head of the Institution)